

## PRESS RELEASE

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Subject line: **Organic electronics: Scientists develop a high-performance unipolar n-type thin-film transistor**

(Tokyo, March 1, 2019) **Researchers at Tokyo Institute of Technology (Tokyo Tech) report a unipolar n-type transistor with a world-leading electron mobility performance of up to  $7.16 \text{ cm}^2 \text{ V}^{-1} \text{ s}^{-1}$ . This achievement heralds an exciting future for organic electronics, including the development of innovative flexible displays and wearable technologies.**

Researchers worldwide are on the hunt for novel materials that can improve the performance of basic components required to develop organic electronics.

Now, a research team at Tokyo Tech's Department of Materials Science and Engineering including Tsuyoshi Michinobu and Yang Wang report a way of increasing the electron mobility of semiconducting polymers, which have previously proven difficult to optimize. Their high-performance material achieves an electron mobility of  $7.16 \text{ cm}^2 \text{ V}^{-1} \text{ s}^{-1}$ , representing more than a 40 percent increase over previous comparable results.

In their study published in the *Journal of the American Chemical Society*, they focused on enhancing the performance of materials known as n-type semiconducting polymers. These n-type (negative) materials are electron dominant, in contrast to p-type (positive) materials that are hole dominant. "As negatively-charged radicals are intrinsically unstable compared to those that are positively charged, producing stable n-type semiconducting polymers has been a major challenge in organic electronics," Michinobu explains.

The research therefore addresses both a fundamental challenge and a practical need. Wang notes that many organic solar cells, for example, are made from p-type semiconducting polymers and n-type fullerene derivatives. The drawback is that the latter are costly, difficult to synthesize and incompatible with flexible devices. "To overcome these disadvantages," he says, "high-performance n-type semiconducting polymers are highly desired to advance research on all-polymer solar cells."

The team's method involved using a series of new poly(benzothiadiazole-naphthalenediimide) derivatives and fine-tuning the material's backbone conformation. This was made possible by the introduction of vinylene bridges<sup>1</sup> capable of forming hydrogen bonds with neighboring fluorine and oxygen atoms. Introducing these vinylene bridges required a technical feat so as to optimize the reaction conditions.

Overall, the resultant material had an improved molecular packaging order and greater strength, which contributed to the increased electron mobility.

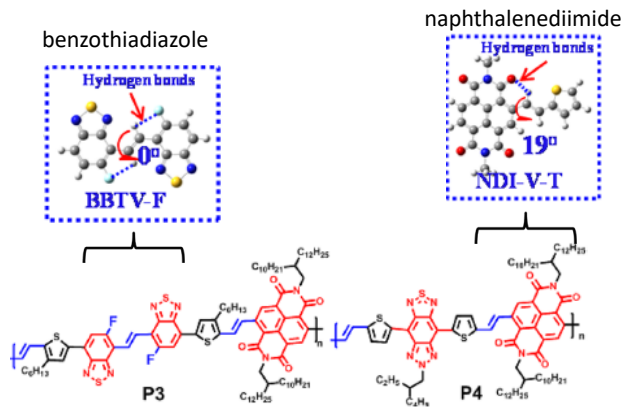
Using techniques such as grazing-incidence wide-angle X-ray scattering (GIWAXS), the researchers confirmed that they achieved an extremely short  $\pi$ - $\pi$  stacking distance<sup>2</sup> of only 3.40 Å. “This value is among the shortest for high mobility organic semiconducting polymers,” says Michinobu.

There are several remaining challenges. “We need to further optimize the backbone structure,” he continues. “At the same time, side chain groups also play a significant role in determining the crystallinity and packing orientation of semiconducting polymers. We still have room for improvement.”

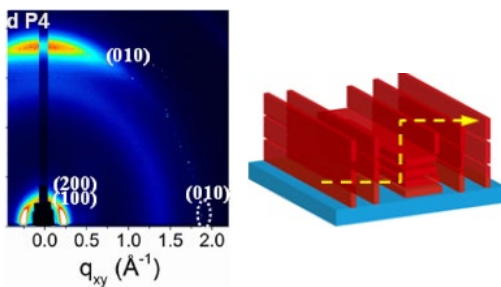
Wang points out that the lowest unoccupied molecular orbital (LUMO) levels were located at -3.8 to -3.9 eV for the reported polymers. “As deeper LUMO levels lead to faster and more stable electron transport, further designs that introduce  $sp^2$ -N, fluorine and chlorine atoms, for example, could help achieve even deeper LUMO levels,” he says.

In future, the researchers will also aim to improve the air stability of n-channel transistors — a crucial issue for realizing practical applications that would include complementary metal-oxide-semiconductor (CMOS)-like logic circuits, all-polymer solar cells, organic photodetectors and organic thermoelectrics.

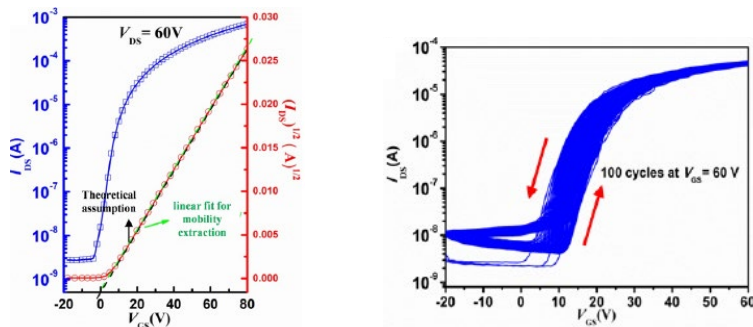
## Development of unipolar n-type transistors



1. Improved coplanarity of polymer backbones via intramolecular hydrogen bonds

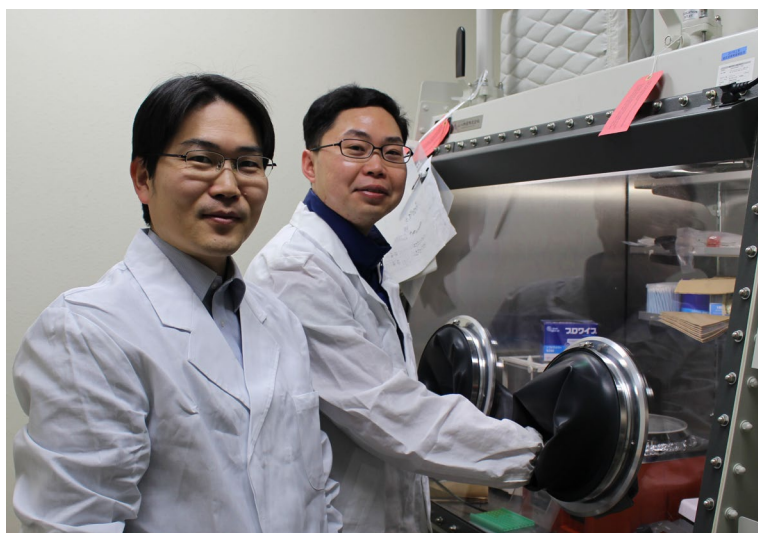


2. Crystalline thin films with the short  $\pi$ - $\pi$  stacking distance of only 3.40  $\text{\AA}$



3. World-leading electron mobility of up to  $7.16\text{ cm}^2\text{ V}^{-1}\text{ s}^{-1}$   
Excellent shelf storage and bias stress stabilities

**Figure 1. Rational design of electron-transporting organic semiconducting polymers and their thin film analysis and transistor performances.**



**Figure 2. Researchers (left: Tsuyoshi Michinobu, right: Yang Wang) fabricating thin-film transistors.**

### Technical terms

<sup>1</sup> Vinylene bridges: Structures that are known to be effective spacers based on previous studies. These spacers had never been used in the context of polymers that were the focus of this study.

<sup>2</sup>  $\pi$ - $\pi$  stacking distance: A measure of how far the charge needs to be carried within the material.

### References

Yang Wang, Tsukasa Hasegawa, Hidetoshi Matsumoto, and Tsuyoshi Michinobu. Significant Improvement of Unipolar n-Type Transistor Performances by Manipulating the Coplanar Backbone Conformation of Electron-Deficient Polymers via Hydrogen Bonding. *Journal of the American Chemical Society* (2019).

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